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Physics of Semiconductor Devices
 Physics of Semiconductor Devices
 Fundamentals of Semiconductor Manufacturing and Process Control
 Power Electronics Handbook
 The Physics of Semiconductors
 Encyclopedia of Information Science and Technology
 With Applications to Optoelectronic Devices
 Semiconductor Material and Device Characterization
 ULSI Devices
 Basic Clinical Radiobiology
 Electronic and Optoelectronic Properties of Semiconductor Structures
 Semiconductor Devices: Physics and Technology, 3rd Edition
 Introduction to the Design of Amplifiers, Receivers and Digital Circuits
 Physics and Technology
 Introduction to the Theory of Computation
 Compound Semiconductors
 MOS Devices for Low-Voltage and Low-Energy Applications
 Semiconductor Device Fundamentals
 Semiconductor Sensors
 Principles of Transistor Circuits
 Modern Power Devices
 Semiconductor Devices, Physics and Technology
 Complete Guide to Semiconductor Devices
 Physics and Technology
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 Semiconductor Device Physics and Design
 Physics, Technology, and Device Concepts
 Semiconductor Optoelectronic Devices
 Vlsi Technology, 2/E
 Physics of Semiconductor Devices
 Fundamentals of Modern VLSI Devices
 Fundamentals of Semiconductor Fabrication
 Introduction to Microelectronic Fabrication
 17th International Workshop on the Physics of Semiconductor Devices 2013
 Principles of Electrical Engineering Materials and Devices
 SEMICONDUCTOR DEVICES: PHYSICS AND TECHNOLOGY, 2ND ED
 Physics, Characteristics, Reliability
 Physics of Semiconductor Devices
 Semiconductor Fundamentals
 PHYSICS OF SEMICONDUCTOR DEVICES, 3RD ED

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Physics of Semiconductor Devices Springer Science & Business Media

This introductory book assumes minimal knowledge of the existence of integrated circuits and of the terminal behavior of electronic components such as resistors, diodes, and MOS and bipolar transistors. It presents to readers the basic information necessary for more advanced processing and design books. Focuses mainly on the basic processes used in fabrication, including lithography, oxidation, diffusion, ion implantation, and thin film deposition. Covers interconnection technology, packaging, and yield. Appropriate for readers interested in the area of fabrication of solid state devices and integrated circuits.

Physics of Semiconductor Devices Springer Science & Business Media

Semiconductor Sensors provides complete coverage of all important aspects of all modern semiconductor sensing devices. It is the only book that offers detailed coverage of the fabrication, characterization, and operational principles of the entire spectrum of devices made from silicon and other semiconductors; and it is written by world-renowned experts in the sensor field. This authoritative guide combines user-friendly organization for quick reference with a masterful pedagogical design that helps build the reader's understanding from section to section and from one chapter to the next. It

begins with a discussion of semiconductor sensor classification and terminology and moves on to a broad description of semiconductor technology, emphasizing bulk and surface micromachining. Senior undergraduate and first-year graduate students will appreciate the 300 illustrations and tables that help to clarify difficult points and encourage visualization of the devices under discussion. They will also benefit from the interdisciplinary nature of the presentation, which encompasses applied physics, chemical engineering, electrical and mechanical engineering, and materials science. For engineers and scientists involved in sensor research and development or in designing sensor-dependent devices and systems, Semiconductor Sensors is the ultimate one-stop source for the latest information on existing technologies.

Fundamentals of Semiconductor Manufacturing and Process Control Wiley-IEEE Press

Learn the basic properties and designs of modern VLSI devices, as well as the factors affecting performance, with this thoroughly updated second edition. The first edition has been widely adopted as a standard textbook in microelectronics in many major US universities and worldwide. The internationally renowned authors highlight the intricate interdependencies and subtle trade-offs between various practically important device parameters, and provide an in-depth discussion of device scaling and scaling limits of CMOS and bipolar devices. Equations and parameters provided are checked continuously against the reality of silicon data, making the book equally useful in practical transistor design and in the classroom. Every chapter has been updated to include the latest developments, such as MOSFET scale length theory, high-field transport model and SiGe-base bipolar devices.

[Power Electronics Handbook](#) CRC Press

Basic Clinical Radiobiology is a concise but comprehensive textbook setting out the essentials of the science and clinical application of radiobiology for those seeking accreditation in radiation oncology, clinical radiation physics, and radiation technology. Fully revised and updated to keep abreast of current developments in radiation biology and radiation oncology, this fifth edition continues to present in an interesting way the biological basis of radiation therapy, discussing the basic principles and significant developments that underlie the latest attempts to improve the radiotherapeutic management of cancer. This new edition is highly illustrated with attractive 2-colour presentation and now includes new chapters on stem cells, tissue response and the convergence of radiotherapy, radiobiology, and physics. It will be invaluable for FRCR (clinical oncology) and equivalent candidates, SpRs (and equivalent) in radiation oncology, practicing radiation oncologists and radiotherapists, as well as radiobiologists and radiotherapy physicists.

The Physics of Semiconductors Semiconductor Devices: Physics and Technology, 3rd Edition Physics and Technology

This book provides an overview of compound semiconductor materials and their technology. After presenting a theoretical background, it describes the relevant material preparation technologies for bulk and thin-layer epitaxial growth. It then briefly discusses the electrical, optical, and structural properties of semiconductors, complemented by a description of the most popular characterization tools, before more complex hetero- and low-dimensional structures are discussed. A special chapter is devoted to GaN and related materials, owing to their huge importance in modern optoelectronic and electronic devices, on the one hand, and their particular properties compared to other compound semiconductors, on the other. In the last part of the book, the physics and functionality of optoelectronic and electronic device structures (LEDs, laser diodes, solar cells, field-effect and heterojunction bipolar transistors) are discussed on the basis of the specific properties of compound semiconductors presented in the preceding chapters of the book. Compound semiconductors form the back-bone of all opto-electronic and electronic devices besides the classical Si electronics. Currently the most important field is solid state lighting with highly efficient LEDs emitting visible light. Also laser diodes of all wavelength ranges between mid-infrared and near ultraviolet have been the enabler for a huge number of unprecedented applications like CDs and DVDs for entertainment and data storage, not to speak about the internet, which would be impossible without optical data communications with infrared laser diodes as key elements. This book provides a concise overview over this class of materials, including the most important technological aspects for their fabrication and characterisation, also covering the most relevant devices based on compound semiconductors. It presents therefore an excellent introduction into this subject not only for students, but also for engineers and scientist who intend to put their focus on this field of science.

Encyclopedia of Information Science and Technology John Wiley & Sons

Helps readers understand the physics behind MOS devices for low-voltage and low-energy applications • Based on timely published and unpublished work written by expert authors • Discusses various promising MOS devices applicable to low-energy environmental and biomedical uses • Describes the physical effects (quantum, tunneling) of MOS devices • Demonstrates the performance of devices, helping readers to choose right devices applicable to an industrial or consumer environment • Addresses some Ge-based devices and other compound-material-based devices for high-frequency applications and future development of high performance devices. 'Seemingly innocuous everyday devices such as smartphones, tablets and services such as on-line gaming or internet keyword searches consume vast amounts of energy. Even when in standby mode, all these devices consume energy. The upcoming "Internet of Things" (IoT) is expected to deploy 60 billion electronic devices spread out in our homes, cars and cities. Britain is already consuming up to 16 per cent of all its power through internet use and this rate is doubling every four years. According to The UK's Daily Mail May (2015), if usage rates continue, all of Britain's power supply could be consumed by internet use in just 20 years. In 2013, U.S. data centers consumed an estimated 91 billion kilowatt-hours of electricity, corresponding to the power generated by seventeen 1000-megawatt nuclear power plants. Data center electricity consumption is projected to increase to roughly 140 billion kilowatt-hours annually by 2020, the equivalent annual output of 50 nuclear power plants. (Natural Resources Defense Council, USA, Feb. 2015) All these examples stress the urgent need for developing electronic devices that consume as little energy as possible. The book "MOS Devices for Low-Voltage and Low-Energy Applications" explores the different transistor options that can be utilized to achieve that goal. It describes in detail the physics and performance of transistors that can be operated at low voltage and consume little power, such as subthreshold operation in bulk transistors, fully depleted SOI devices, tunnel FETs, multigate and gate-all-around MOSFETs. Examples of low-energy circuits making use of these devices are given as well. The book "MOS Devices for Low-Voltage and Low-Energy Applications" is a good reference for graduate students, researchers, semiconductor and electrical engineers who will design the electronic systems of tomorrow.' --- Dr. Jean-Pierre Colinge, Taiwan Semiconductor Manufacturing Company (TSMC) "The authors present a creative way to show how different MOS devices can be used for low-voltage and low-power applications. They start with Bulk MOSFET, following with SOI MOSFET, FinFET, gate-all-around MOSFET, Tunnel-FET and others. It is presented the physics behind the devices, models, simulations, experimental results and applications. This book is interesting for researchers, graduate and undergraduate students. The low-energy field is an important topic for integrated circuits in the future and none can stay out of this." --- Prof. Joao A. Martino, University of Sao Paulo, Brazil

With Applications to Optoelectronic Devices Springer Science & Business Media

A practical guide to semiconductor manufacturing from process control to yield modeling and experimental design Fundamentals of Semiconductor Manufacturing and Process Control covers all issues involved in manufacturing microelectronic devices and circuits, including fabrication sequences, process control, experimental design, process modeling, yield modeling, and CIM/CAM systems. Readers are introduced to both the theory and practice of all basic manufacturing concepts. Following an overview of manufacturing and technology, the text explores process monitoring methods, including those that focus on product wafers and those that focus on the equipment used to produce wafers. Next, the text sets forth some fundamentals of statistics and yield modeling, which set the foundation for a detailed discussion of how statistical process control is used to analyze quality and improve yields. The discussion of statistical experimental design offers readers a powerful approach for systematically varying controllable process conditions and determining their impact on output parameters that measure quality. The authors introduce process modeling concepts, including several advanced process control topics such as run-by-run, supervisory control, and process and equipment diagnosis. Critical coverage includes the following: * Combines process control and semiconductor manufacturing * Unique treatment of system and software

technology and management of overall manufacturing systems * Chapters include case studies, sample problems, and suggested exercises * Instructor support includes electronic copies of the figures and an instructor's manual Graduate-level students and industrial practitioners will benefit from the detailed examination of how electronic materials and supplies are converted into finished integrated circuits and electronic products in a high-volume manufacturing environment. An Instructor's Manual presenting detailed solutions to all the problems in the book is available from the Wiley editorial department. An Instructor Support FTP site is also available.

Semiconductor Material and Device Characterization Springer

Market_Desc: · Electrical Engineers· Scientists Special Features: · Provides strong coverage of all key semiconductor devices. Includes basic physics and material properties of key semiconductors· Covers all important processing technologies About The Book: This book is an introduction to the physical principles of modern semiconductor devices and their advanced fabrication technology. It begins with a brief historical review of major devices and key technologies and is then divided into three sections: semiconductor material properties, physics of semiconductor devices and processing technology to fabricate these semiconductor devices.

ULSI Devices Elsevier

"Intended as an upper-level undergraduate or introductory graduate text in computer science theory," this book lucidly covers the key concepts and theorems of the theory of computation. The presentation is remarkably clear; for example, the "proof idea," which offers the reader an intuitive feel for how the proof was constructed, accompanies many of the theorems and a proof. Introduction to the Theory of Computation covers the usual topics for this type of text plus it features a solid section on complexity theory--including an entire chapter on space complexity. The final chapter introduces more advanced topics, such as the discussion of complexity classes associated with probabilistic algorithms.

Basic Clinical Radiobiology John Wiley & Sons

Market_Desc: · Design Engineers· Research Scientists· Industrial and Electronics Engineering Managers· Graduate Students Special Features: · Completely updated with 30-50% revisions· Will include worked examples and end-of-the-chapter problems (with a solutions manual)· First edition was the most cited work in contemporary engineering and applied science publications (over 12000 citations since 1969) About The Book: This classic reference provides detailed information on the underlying physics and operational characteristics of all major bipolar, unipolar, special microwave, and optoelectronic devices. It integrates nearly 1,000 references to important original research papers and review articles, and includes more than 650 high-quality technical illustrations and 25 tables of material parameters for device analysis.

Electronic and Optoelectronic Properties of Semiconductor Structures Wiley-Interscience

Resistivity -- Carrier and doping density -- Contact resistance and Schottky barriers -- Series resistance, channel length and width, and threshold voltage -- Defects -- Oxide and interface trapped charges, oxide thickness -- Carrier lifetimes -- Mobility -- Charge-based and probe characterization -- Optical characterization -- Chemical and physical characterization -- Reliability and failure analysis.

Semiconductor Devices: Physics and Technology, 3rd Edition Tata McGraw-Hill Education

The purpose of this book is to provide the reader with a self-contained treatment of fundamental solid state and semiconductor device physics. The material presented in the text is based upon the lecture notes of a one-year graduate course sequence taught by this author for many years in the Department of Electrical Engineering of the University of Florida. It is intended as an introductory textbook for graduate students in electrical engineering. However, many students from other disciplines and backgrounds such as chemical engineering, materials science, and physics have also taken this course sequence, and will be interested in the material presented herein. This book may also serve as a general reference for device engineers in the semiconductor industry. The present volume covers a wide variety of topics on basic solid state physics and physical principles of various semiconductor devices. The main subjects covered include crystal structures, lattice dynamics, semiconductor statistics, energy band theory, excess carrier phenomena and recombination mechanisms, carrier transport and scattering mechanisms, optical properties, photoelectric effects, metal-semiconductor devices, the p-n junction diode, bipolar junction transistor, MOS devices, photonic devices, quantum effect devices, and high speed III-V semiconductor devices. The text presents a unified and balanced treatment of the physics of semiconductor materials and devices. It is intended to provide physicists and materials scientists with more device backgrounds, and device engineers with a broader knowledge of fundamental solid state physics.

Introduction to the Design of Amplifiers, Receivers and Digital Circuits John Wiley & Sons

Semiconductor power devices are the heart of power electronics. They determine the performance of power converters and allow topologies with high efficiency. Semiconductor properties, pn-junctions and the physical phenomena for understanding power devices are discussed in depth. Working principles of state-of-the-art power diodes, thyristors, MOSFETs and IGBTs are explained in detail, as well as key aspects of semiconductor device production technology. In practice, not only the semiconductor, but also the thermal and mechanical properties of packaging and interconnection technologies are essential to predict device behavior in circuits. Wear and aging mechanisms are identified and reliability analyses principles are developed. Unique information on destructive mechanisms, including typical failure pictures, allows assessment of the ruggedness of power devices. Also parasitic effects, such as device induced electromagnetic interference problems, are addressed. The book concludes with modern power electronic system integration techniques and trends.

Physics and Technology Springer

Principles of Electrical Engineering Materials and Devices has been developed to bridge the gap between traditional electronic circuits texts and semiconductor texts

Introduction to the Theory of Computation John Wiley & Sons

Graduate text with comprehensive treatment of semiconductor device physics and engineering, and descriptions of real optoelectronic devices.

Compound Semiconductors Elsevier

Written in a tutorial form, the text supplies in-depth the physics, design, and fabrication technology for power devices. Each chapter includes a discussion of the basic concepts of device operation and their electrical characteristics, a detailed analysis of the device physics, and the technology

of fabrication. Extensive analytical solutions are used to enable the reader to obtain an understanding of the physics.

MOS Devices for Low-Voltage and Low-Energy Applications McGraw-Hill Science, Engineering & Mathematics

The purpose of this workshop is to spread the vast amount of information available on semiconductor physics to every possible field throughout the scientific community. As a result, the latest findings, research and discoveries can be quickly disseminated. This workshop provides all participating research groups with an excellent platform for interaction and collaboration with other members of their respective scientific community. This workshop's technical sessions include various current and significant topics for applications and scientific developments, including • Optoelectronics • VLSI & ULSI Technology • Photovoltaics • MEMS & Sensors • Device Modeling and Simulation • High Frequency/ Power Devices • Nanotechnology and Emerging Areas • Organic Electronics • Displays and Lighting Many eminent scientists from various national and international organizations are actively participating with their latest research works and also equally supporting this mega event by joining the various organizing committees.

Semiconductor Device Fundamentals Prentice Hall

"This set of books represents a detailed compendium of authoritative, research-based entries that define the contemporary state of knowledge on

technology"--Provided by publisher.

Semiconductor Sensors Wiley Global Education

Semiconductor Device Physics and Design teaches readers how to approach device design from the point of view of someone who wants to improve devices and can see the opportunity and challenges. It begins with coverage of basic physics concepts, including the physics behind polar heterostructures and strained heterostructures. The book then details the important devices ranging from p-n diodes to bipolar and field effect devices. By relating device design to device performance and then relating device needs to system use the student can see how device design works in the real world.

Principles of Transistor Circuits Wiley-Interscience

This book is an introduction to the physical principles of modern semiconductor devices and their advanced fabrication technology. It begins with a brief historical review of major devices and key technologies and is then divided into three sections: semiconductor material properties, physics of semiconductor devices and processing technology to fabricate these semiconductor devices.

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